## ARTICLES

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## Coherent control of individual electron spins in a two-dimensional quantum dot array

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## Device architecture



- (Homemade) Dilution refrigerator: $\mathrm{T} \sim 60 \mathrm{mK}$ - Static out-of-plane magnetic field
- 9 dots:
- GaAs/AIGaAs heterostructure
- 28 Gates: light blue and red ones are plungers other gates are used as barriers/tunnel
- 4 Quantum Point Contact (in the edges)

Loading sequence (up to 2 electrons)


- Load electron to TL dot (standard single dot charge stability diagram):
- $L_{1}: 1$ electron
- $\mathrm{L}_{\mathrm{s}}$ : singlet state
- I: isolate the QD from the reservoir or perform readout
- Loading fidelity decreases with the number of electron $n$


## Loading sequence（more than 2 electrons）



## Single-electron charge config. in the array of 9 dots

Virtual gates are define such as:

$$
\left[\begin{array}{l}
\delta V_{\mathrm{X}}^{+} \\
\delta V_{\mathrm{X}}^{-} \\
\delta V_{\mathrm{Y}}^{+} \\
\delta V_{\mathrm{Y}}^{-}
\end{array}\right]=\left[\begin{array}{cccc}
C_{\mathrm{L}}^{\mathrm{L}} / C_{\mathrm{R}}^{\mathrm{R}} & 1 & 0 & 0 \\
-C_{\mathrm{L}}^{\mathrm{L}} / C_{\mathrm{R}}^{\mathrm{R}} & 1 & 0 & 0 \\
0 & 0 & C_{\mathrm{B}}^{\mathrm{B}} / C_{\mathrm{T}}^{\mathrm{T}} & 1 \\
0 & 0 & -C_{\mathrm{B}}^{\mathrm{B}} / C_{\mathrm{T}}^{\mathrm{T}} & 1
\end{array}\right]\left[\begin{array}{c}
\delta V_{\mathrm{L}} \\
\delta V_{\mathrm{R}} \\
\delta V_{\mathrm{B}} \\
\delta V_{\mathrm{T}}
\end{array}\right]
$$



- Goal is to mimic electric dipole behavior
- But another way to see it: Gates+ shift the energy level of the dots simultaneously Gates- move the electron from one side to the other


## Single－electron charge config．in the array of 9 dots

$$
\delta V_{x}^{-}(\mathrm{V})
$$



Inset：simulation using a constant interaction model

## Single－electron charge config．in the array of 9 dots

$$
V_{\mathrm{R}}(\mathrm{~V})
$$



Inset：simulation using a constant interaction model

## Single－electron charge config．in the array of 9 dots




Inset：simulation using a constant interaction model

## Single-electron charge config. in the array of 9 dots



## Multiple electrons charge configuration





1. Load 5 electrons
2. Record a stability diagram varying $\delta \mathrm{V}^{-}{ }_{\mathrm{X} ; \mathrm{y}}$
3. Identify ( $1,1,1,1,1$ ): highest symmetry point

## Multiple electrons charge configuration





1. Load 5 electrons
2. Record a stability diagram varying $\delta \mathrm{V}^{-}{ }_{\mathrm{X} ; \mathrm{Y}}$
3. Identify ( $1,1,1,1,1$ ): highest symmetry point
4. Load 4 more electrons in the corners

## 2 Spins manipulations: energy diagrams

Low exchange interaction


High exchange interaction



- When the 2 electrons are in the same dot, the singlet state is the ground state
- Otherwise, the ground state is the triplet $\mathrm{T}_{+}$
- At P2, we get a mixture of $\mathrm{T}_{0}(1,1)$ and $\mathrm{S}(1,1)$


## 2 Spins manipulations: Spin mixing map


$\delta V_{\text {L-TL }}(\mathrm{V})$

Method:

- Start with a singlet in TL
- Pulse in a given gate configuration
- Read the state
- Repeat this 1000 time to get $\mathrm{P}_{\mathrm{S}}$


The spin mixing area (white/yellow) correspond to weakly T Tunnel coupled dots (or to $S(2,0)$ and $T_{+}(1,1)$ mixing)

## 2 Spins manipulations: Spin mixing map



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The spin mixing area (white/yellow) correspond to weakly
©
=> Possible to tune the coupling of 2 dots inside the array (i.e. go from a decoupled regime to high exchange one and oppositely)
tunnel coupled dots (or to $S(2,0)$ and $T_{+}(1,1)$ mixing)

## 2 Spins manipulations：Spin mixing map



## 2 Spins manipulations: Spin mixing map



Method:

- Start with a singlet in TL
- Move it to C
- Pulse in a given gate configuration (50 ns)
- Read the state
- Repeat this 150 time to get $\mathrm{P}_{\mathrm{S}}$



## 2 Spins manipulations: Spin mixing map



Method:

- Start with a singlet in TL
- Move it to C
- Pulse in a given gate configuration (50 ns)
- Read the state

- Repeat this 150 time to get $P_{S}$

The high $P_{S}$ probability area (blue) correspond to transfer the 2 electrons in another dot, preserving the singlet state. The mixing area (red) are where the electrons are split in 2 dots (and we have a mixture of $S(1,1)$ and $T_{0}(1,1)$
=> Possible to coherently displace spins

## Coherent exchange oscillations




- Similarly do a spin map corresponding to T and C .
- Apply a poltage pulse sequence to pulse the tunnel barrier interaction in order to perform coherent exchange
 oscillations*
=> Coherent time of 100 ns
*See Bertrand, B. et al. Quantum manipulation of two-electron spin states in isolated double quantum dots. Phys. Rev. Lett. 115, 096801 (2015).


## Coherent exchange oscillations



## Conclusion

Summary of results:

- Loading and displacement of a single electron in the QD array
- Loading and (simple) displacement of up to 9 electrons
- 2 electron spin readout from any QD
- Local coherent spin oscillation between 2 dots of the array


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My personal opinion:

- Pragmatic approach to start to work on QD array
- But difficult to scale up


## Thanks

Thank you for your attention!

## 2 Spins manipulations：Spin mixing maps



